

RF GaN Semiconductor Device Market to Cross USD 6.45 Billion by 2031, Due to Booming IT & Telecommunication Demand

RF GaN Semiconductor Device Market Size, Share, Growth Drivers and Regional Analysis, Global Forecast 2024 - 2031

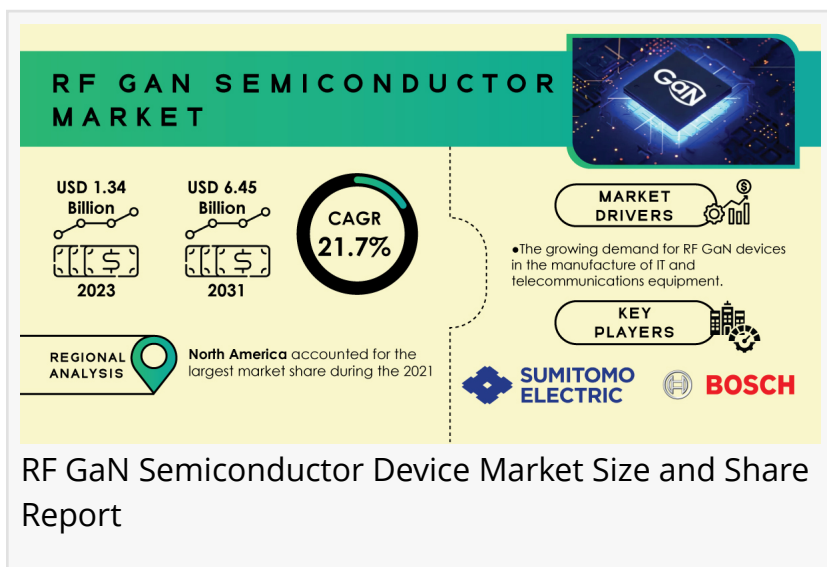
AUSTIN, TEXAS, UNITED STATES, April 11, 2024 /EINPresswire.com/ -- Market Size & Report Scope:

According to The SNS Insider report the RF GaN Semiconductor Device Market Size was USD 1.34 Billion in 2023 and is expected to reach USD 6.45 Billion by 2031, growing at a significant CAGR of 21.7% over the forecast period 2024-2031. Growing emphasis on local manufacturing to minimize operational costs and cater to regional demands creates a favorable market landscape.

RF GaN, a revolutionary technology, offers superior high-power density performance in power electronics applications. RF-based power amplifiers are important components in the transmitter circuitry of various services and products. GaN's wide bandgap translates to a high breakdown field, enabling GaN devices to operate at higher voltages compared to conventional semiconductors.

The growing Internet of Things (IoT) necessitates increasing data transfer across networks without human intervention. This widespread IoT adoption will lead to signal congestion, necessitating GaN technology's ability to amplify power, capacity, and bandwidth for efficient communication between interconnected devices. The development of Microelectromechanical Systems (MEMS) technology, an integral part of IoT devices, will positively impact the GaN RF semiconductor device market.

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Top Companies Featured in RF GaN Semiconductor Device Market Report:

- Sumitomo Electric Industries
- Robert Bosch
- Toshiba Corporation
- Infineon Technologies
- Microchip Technology
- Raytheon Company
- STMicroelectronics
- Mitsubishi Electric Corporation
- Panasonic Corporation
- NXP Semiconductor

Market Analysis:

The RF GaN Semiconductor Device Market is driven by the, High Demand from the RF Semiconductor Industry, Communication across various applications are depends on electronic devices operating at specific frequencies. GaN's exceptional ability to deliver high power amplification at very high frequencies has made it a frontrunner in the RF power semiconductor device market. The development of GaN-based Monolithic Microwave Integrated Circuits (MMICs) has further accelerated the adoption of GaN for RF applications. The continuously growing demand for electric vehicle (EV) and hybrid electric vehicle (HEV) market presents lucrative growth prospects for the GaN semiconductor device market. GaN power and opto-semiconductor devices have immense potential in the power and optoelectronic systems used in EVs and HEVs. The rising demand for GaN semiconductor devices in control systems, motor drives, braking systems, lighting, and instrumentation within EVs and HEVs fuels market revenue. The increasing competition from SiC, which Increase the higher thermal conductivity than GaN, can potentially hamper the market share of GaN RF semiconductors.

RF GaN Semiconductor Device Market Segmentation as Follows:

By Material:

The GaN-On-Sic segment dominated the market, with holding highest share of market, due to its excellent thermal conductivity, enabling efficient heat dissipation and facilitating high-power operation. This characteristic makes GaN-On-SiC ideal for high-performance applications in base stations and radar systems.

BY MATERIAL

- GaN-On-Silicon
- GaN-On-Sic
- GaN-On-Diamond

By Application:

In 2023, the Wireless Infrastructure segment Dominates market with securing the leading market

share. The ever-growing demand for data and the subsequent expansion of commercial networks are driving network carriers to adopt next-generation LTE networks, such as 4G and 5G. GaN RF technology, with its ability to deliver higher frequency data bandwidth connections, is rapidly becoming the preferred choice for network service providers. GaN RF devices ensure maximum frequency generation at the required band while preventing interference from other frequencies. This allows for faster data transfer speeds, enabling activities like online gaming and video streaming.

BY APPLICATION

- Wireless infrastructure
- Satellite communication
- Power storage
- PV inverted
- Others

By End-User:

On the basis of end user the Aerospace & Defense segment hold the highest market share. GaN's superior power density, high efficiency, and wide bandwidth make it ideal for various defense applications such as radar systems, electronic warfare equipment, and communication systems. The GaN's radiation hardness allows it to function reliably in harsh environments.

BY END-USER

- IT & telecom
- Automotive
- Aerospace & defense
- Consumer electronics
- Others

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Impact of Russia-Ukraine War:

The conflict between Russia and Ukraine has disrupted global supply chains and caused significant volatility in energy prices. This has had a cascading effect on the RF GaN Semiconductor Device Market, Ukraine is a major source of raw materials Important for GaN production. The war has hampered the smooth flow of these materials, leading to potential shortages and growing prices. The Growing in energy prices due to the war has inflated production costs for GaN devices, potentially impacting profit margins for manufacturers. Governments may prioritize defense spending over infrastructure projects that utilize GaN technology, leading to a temporary slowdown in market growth.

Impact of Economic Downturn:

A potential global economic slowdown could dampen the growth of the RF GaN Semiconductor Device Market, an economic downturn could lead to decreased consumer spending, impacting the demand for electronics containing GaN devices, such as smartphones and laptops. The Companies may become more cautious about investing in new technologies such as GaN during an economic slowdown, hindering market expansion.

Regional Analysis:

The North America Region commanded the largest market share due to the presence of prominent RF GaN device manufacturers, strong government support for technological advancements, and a large consumer base with a high demand for sophisticated electronics. Asia Pacific is expected to growing with the highest CAGR during the forecast period. This is attributed to Rapidly growing economies with rising disposable incomes, increasing government initiatives to promote domestic GaN development. Expanding consumer electronics and automotive industries in the region, and Growing demand for 5G infrastructure.

Key Takeaways for the RF GaN Semiconductor Device Market:

- Technological advancements and increasing demand for high-performance electronics will continue to drive market growth.
- The impact of the Russia-Ukraine war and potential economic downturn creates uncertainties that require close monitoring.
- Asia Pacific is expected to be the fastest-growing market, fueled by economic expansion and government support.

Recent Developments:

- May 2023: Qorvo, Inc. announced the launch of a new series of GaN transistors designed for high-power density applications in radar and communication systems.
- February 2023: MACOM Technology Solutions Holdings Inc. unveiled a new family of GaN HEMT transistors specifically engineered for use in 5G base stations and next-generation radar systems.
- December 2022: NXP Semiconductors announced a collaboration with a leading Asian foundry to expand its GaN on SiC manufacturing capabilities to meet the growing demand for next-generation GaN devices.

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Akash Anand

SNS Insider Pvt. Ltd

+1 415-230-0044

info@snsinsider.com

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